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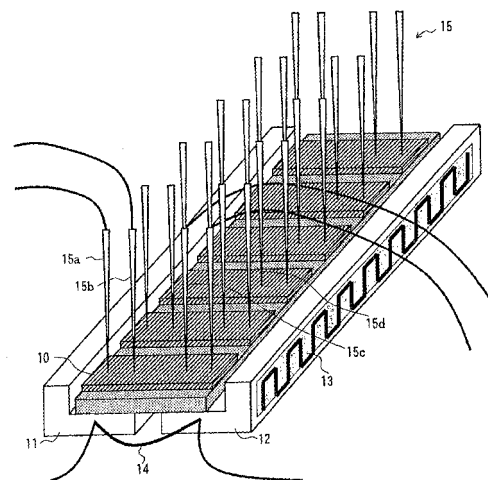
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(54) **METHOD AND DEVICE FOR MEASURING THERMOELECTRIC CHARACTERISTICS OF
COMBINATORIAL SPECIMEN**

(57) The present invention provides a method and device for measuring thermoelectric characteristics of a combinatorial sample, wherein the method and device are useful for rapid sample evaluation, the investigation of thermoelectric materials, and the carrier control of semiconductors.

The device includes combinatorial samples (10) patterned with a metal mask, a pair of sample holders (11 and 12) for applying a small temperature gradient to the sample (10), a thermocouple (14) for measuring the temperature gradient, and a probe pin array (15) in contact with the sample (10).

FIG. 2



Description

Technical Field

[0001] The present invention relates to a method and device for measuring thermoelectric characteristics of a combinatorial sample.

Background Art

[0002] Recently, the use of waste energy has become a focus of attention, because the following problems have been in progress: the depletion of fossil energy resources, global warming, and air pollution. Since thermoelectric materials can be used for converting waste heat into electrical energy, electrical energy can be efficiently generated with conventional electric power-generating systems including such thermoelectric materials. Therefore, it is expected that new thermoelectric materials having higher efficiency are developed. Since a junction is cooled by the Peltier effect when a current is applied to a thermoelectric material, such a material is used for cooling systems. Therefore, demands have been made on new thermoelectric materials having higher efficiency.

[0003] Furthermore, the following new semiconductors have been recently developed at a feverish pace: wide-gap semiconductors, transparent semiconductors, and organic semiconductors. Carrier control is the key to use such semiconductors for devices. Various devices such as transistors, FETs, diodes, and solar cells, laser oscillators can be manufactured using, for example, junctions (pn junctions) consisting of p-type semiconductors, in which the major carriers are holes, and n-type semiconductors, in which the major carriers are electrons. Therefore, the carrier type is particularly a critical property parameter.

[0004] Carrier control is usually performed in such a manner that an undoped sample is subjected to impurity substitution or is heat-treated in an impurity gas atmosphere. However, since the dose is very small, the control is not easy and therefore such treatment is performed by trial and error in many cases. In particular, when the wide-gap semiconductors are treated, either a p type or an n type is apt to be obtained. Therefore, only either type has been fabricated and the conditions of fabrication are strictly limited. Thus, it is necessary to investigate more precise growing conditions and doping conditions.

Disclosure of Invention

[0005] In the conventional investigation of thermoelectric materials, a large amount of time has been wasted because such materials are prepared one by one and the thermoelectric characteristics thereof are individually evaluated.

[0006] In particular, when combinatorial thin film syn-

thesis is employed, the evaluation method of thermoelectric characteristics is a critical factor and therefore it is necessary to continuously measure a large number of prepared minute samples at high speed.

[0007] In the investigation of doping conditions for controlling semiconductor carriers, the Hall resistance and electrical resistance of samples prepared one by one have been individually measured. However, there are the following problems: (1) it takes a long time to evaluate samples because the samples are measured one by one, and (2) the evaluation is not easy because a large magnetic field generator must be used and therefore an instrument is expensive and large.

[0008] In order to solve the above problems, it is an object of the present invention to provide a method and device for measuring thermoelectric characteristics of a combinatorial sample, wherein the method and device are useful for rapid sample evaluation, the investigation of thermoelectric materials, and the carrier control of semiconductors.

[0009] In order to achieve the above object, the present invention provides the following method and device.

(1) A method for measuring thermoelectric characteristics of a combinatorial sample includes a step of applying a small temperature gradient to a patterned combinatorial sample, disposed between two or more hot baths, to obtain a plurality of electrical signals from the combinatorial sample.

(2) A device for measuring thermoelectric characteristics of a combinatorial sample includes a patterned combinatorial sample, two or more hot baths for applying a small temperature gradient to the sample, a means for measuring the temperature gradient, and a component for obtaining a plurality of electrical signals in the temperature gradient direction, the component being in contact with or being connected to the sample.

[0010] The term "hot baths" is herein defined as portions of sample holders. The sample holders do not include simple (sample) holders but include holders having a certain heat capacity so as to maintain the temperature at a constant value during measurement (the holders are actually made of metal such as copper but are not made of, for example, plastic and so on having a small heat capacity). When the relationship between the electrical resistance and the temperature are determined, one hot bath is used. However, when the thermoelectric characteristics are measured, two hot baths must be used.

[0011] According to a particular configuration of the present invention, the method for measuring thermoelectric characteristics of a combinatorial sample includes a step of applying a small temperature gradient to a combinatorial sample, patterned by a photolithographic process, to obtain a plurality of electrical signals

from the combinatorial sample by wire-bonding.

[0012] The device for measuring thermoelectric characteristics of a combinatorial sample includes a combinatorial sample patterned by a photolithographic process, a pair of sample holders for applying a small temperature gradient to the sample, a means for measuring the temperature gradient, and a wire-bonding means connected to the sample.

Brief Description of the Drawings

[0013]

FIG. 1 is a block diagram showing a combinatorial thermoelectric characteristic-measuring device, wherein the device is an example of the present invention.

FIG. 2 is a perspective view showing a combinatorial thermoelectric characteristic-measuring device including a probe pin array, wherein the device is a first example of the present invention.

FIG. 3 is a perspective view showing a combinatorial thermoelectric characteristic-measuring device including bonding wires, wherein the device is a second example of the present invention.

FIG. 4 is a graph showing the thermoelectromotive force obtained with a device of the present invention.

Best Mode for Carrying out the Invention

[0014] An embodiment of the present invention will now be described in detail.

[0015] FIG. 1 is a block diagram showing a combinatorial thermoelectric characteristic-measuring device, wherein the device is an example of the present invention.

[0016] In this figure, reference numeral 1 represents a sample stage, reference numeral 2 represents a temperature controller, reference numeral 3 represents a temperature difference controller, reference numeral 4 represents a voltmeter, reference numeral 5 represents an ammeter, reference numeral 6 represents a line-switching unit, and reference numeral 7 represents a computer.

[0017] FIG. 2 is a perspective view showing a measuring section of a combinatorial thermoelectric characteristic-measuring system, wherein the measuring section is a first example of the present invention.

[0018] In this figure, reference numeral 10 represents two-dimensional combinatorial samples (micro-samples) patterned using a metal mask; reference numerals 11 and 12 represent a pair of sample holders for supporting the samples 10; reference numeral 13 represents a heater disposed on the side of each sample holder; reference numeral 14 represents a thermocouple disposed between a pair of the sample holders 11 and 12; and reference numeral 15 represents a probe

pin array arranged so as to be uniformly in contact with a plurality of the combinatorial samples 10 arranged in a line.

[0019] A small temperature gradient (for example, a gradient in which the temperature of one sample holder 12 is 3°C higher than that of the other sample holder 11) is applied to the samples 10, patterned using the metal mask, with the heater 13, and thereby a plurality of electrical signals can be obtained from the combinatorial samples 10 with the probe pin array 15 in contact with the samples 10.

[0020] Combinatorial thermoelectric characteristics of the samples can be measured under the same conditions in one operation in such a manner that four probe pins 15a, 15b, 15c, and 15d are arranged in a line and a current is applied between the probe pins 15a and 15d to measure the potential difference between the probe pins 15b and 15c.

[0021] After the two-dimensional combinatorial samples used for the measurement is removed from the sample holders 11 and 12, other two-dimensional combinatorial samples can be mounted thereon and then measured under the same conditions.

[0022] FIG. 3 is a perspective view showing a measuring section of a combinatorial thermoelectric characteristic-measuring system, wherein the measuring section is a second example of the present invention.

[0023] In this example, bonding wires for connection are used instead of the probe pin array of the first example.

[0024] In this figure, reference numeral 20 represents a two-dimensionally arranged combinatorial sample patterned by a photolithographic process, reference numerals 21 and 22 represent a pair of sample holders for supporting the sample 20, reference numeral 23 represents a heater disposed on the side of each sample holder, reference numeral 24 represents a thermocouple disposed between a pair of the sample holders 21 and 22, reference numeral 25 represents bonding terminals, and reference numeral 26 represents bonding wires disposed between the bonding terminals 25 and the sample 20.

[0025] A small temperature gradient is applied to the sample 20, patterned by the photolithographic process, with the heater 23, and thereby a plurality of electrical signals can be obtained from the combinatorial sample 20 via the bonding terminal 25 by a wire bonding process using the bonding wires 26.

[0026] FIG. 4 is a graph showing the thermoelectromotive force obtained with a device of the present invention. The vertical axis represents the temperature difference [ΔT (°C)] and the horizontal axis represents the thermoelectromotive force (μV).

[0027] As shown in this figure, the thermoelectromotive force varies linearly with the temperature difference. Thus, this proves that the measurement is correct.

[0028] According to the present invention, the following advantages can be obtained.

(1) A small temperature gradient is applied to samples patterned using a metal mask and probe pins are caused to be in contact with the samples, thereby obtaining a large number of electrical signals from the combinatorial samples.

(2) A small temperature gradient is applied to a sample patterned by a photolithographic process, thereby obtaining a large number of electrical signals from the combinatorial sample using bonding wires.

[0029] According to the present invention, in a sample prepared by combinatorial thin film synthesis, a large number of data can be obtained from the measurement of the thermoelectromotive force and the electrical resistance. Thereby, high-speed screening is possible when thermoelectric materials are investigated. Thus, the device according to the present invention is an important factor in investigating thermoelectric materials.

[0030] The combinatorial thin-film synthesis using a mask system is a high-speed thermoelectric material-investigating technique and has sprung into wide use. When thermoelectric materials are investigated using this technique, it takes a long time to evaluate prepared thin-films, of which the thermoelectric characteristics are measured, because the thin-films are individually subjected to the measurement.

[0031] According to the present invention, the thermoelectromotive force and electrical characteristics of thin-films prepared by the combinatorial synthesis can be simultaneously measured, thereby performing the high-speed evaluation of such electrical characteristics. The device can be used in various applications. For example, when carriers are introduced into semiconductors, the device can be used for readily determining whether the charge of the introduced carriers is positive or negative.

[0032] In the above examples, two hot baths are used. However, two or more hot baths may be used.

[0033] The present invention is not limited to the above examples and various modifications may be performed within the scope of the present invention. It is construed that the present invention covers such modifications.

[0034] As described above, according to the present invention, since the thermoelectromotive force and electrical characteristics of thin-films prepared by the combinatorial synthesis can be simultaneously measured, the high-speed evaluation of such electrical characteristics can be performed. Thus, the device according to the present invention is an important factor in investigating thermoelectric materials.

[0035] The present invention can be used in various applications. For example, when carriers are introduced into semiconductors, the present invention can be used for readily determining whether the charge of the introduced carriers is positive or negative.

Industrial Applicability

[0036] According to the present invention, a method and device for measuring thermoelectric characteristics of a combinatorial sample are important factors in investigating thermoelectric materials. The method and the device can be used in various applications. For example, when carriers are introduced into semiconductors, the method and the device can be used for readily determining whether the charge of the introduced carriers is positive or negative.

Claims

1. A method for measuring thermoelectric characteristics of a combinatorial sample, comprising a step of applying a small temperature gradient to a patterned combinatorial sample disposed between two or more hot baths to obtain a plurality of electrical signals from the combinatorial sample.
2. A device for measuring thermoelectric characteristics of a combinatorial sample, comprising:
 - (a) a patterned combinatorial sample;
 - (b) two or more hot baths for applying a small temperature gradient to the sample;
 - (c) a means for measuring the temperature gradient; and
 - (d) a component for obtaining a plurality of electrical signals in the temperature gradient direction, the component being in contact with or being connected to the sample.

FIG. 1

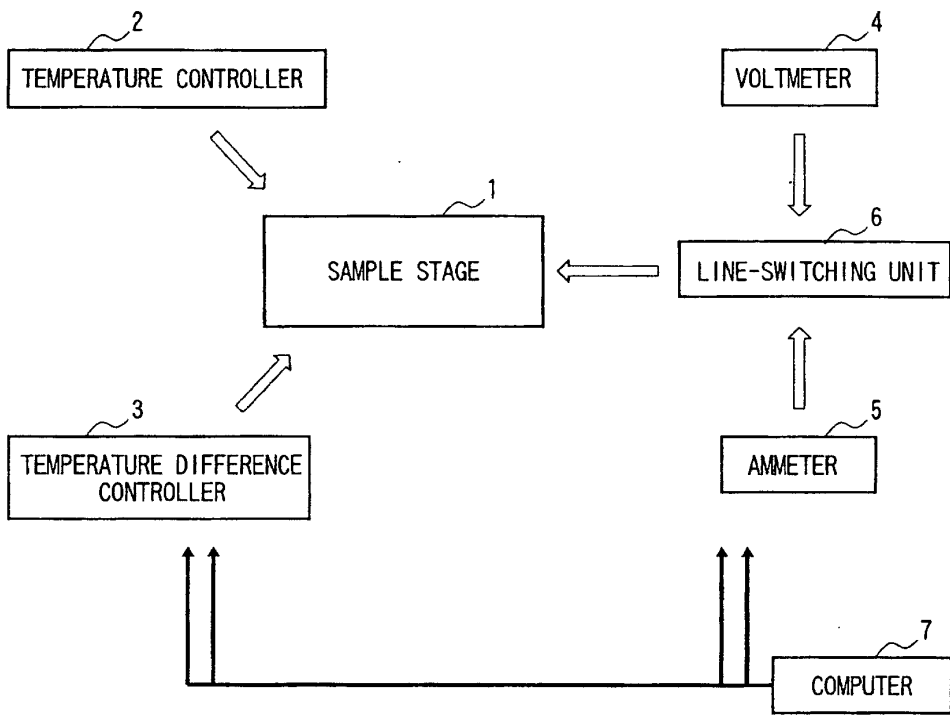


FIG. 2

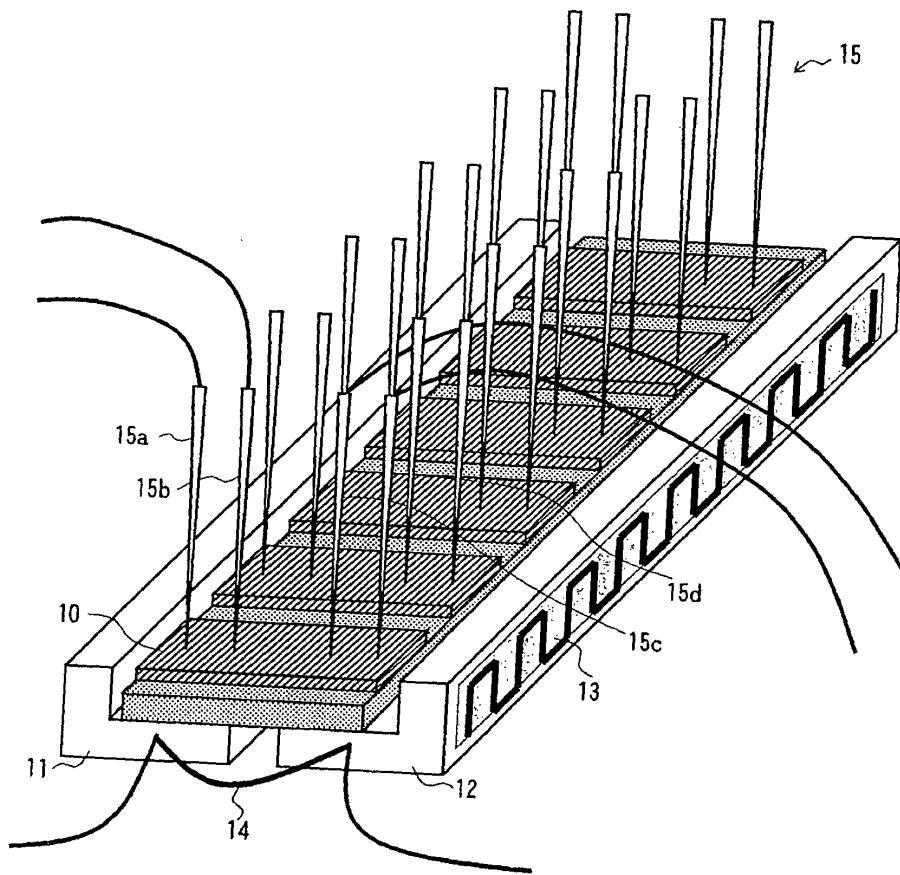


FIG. 3

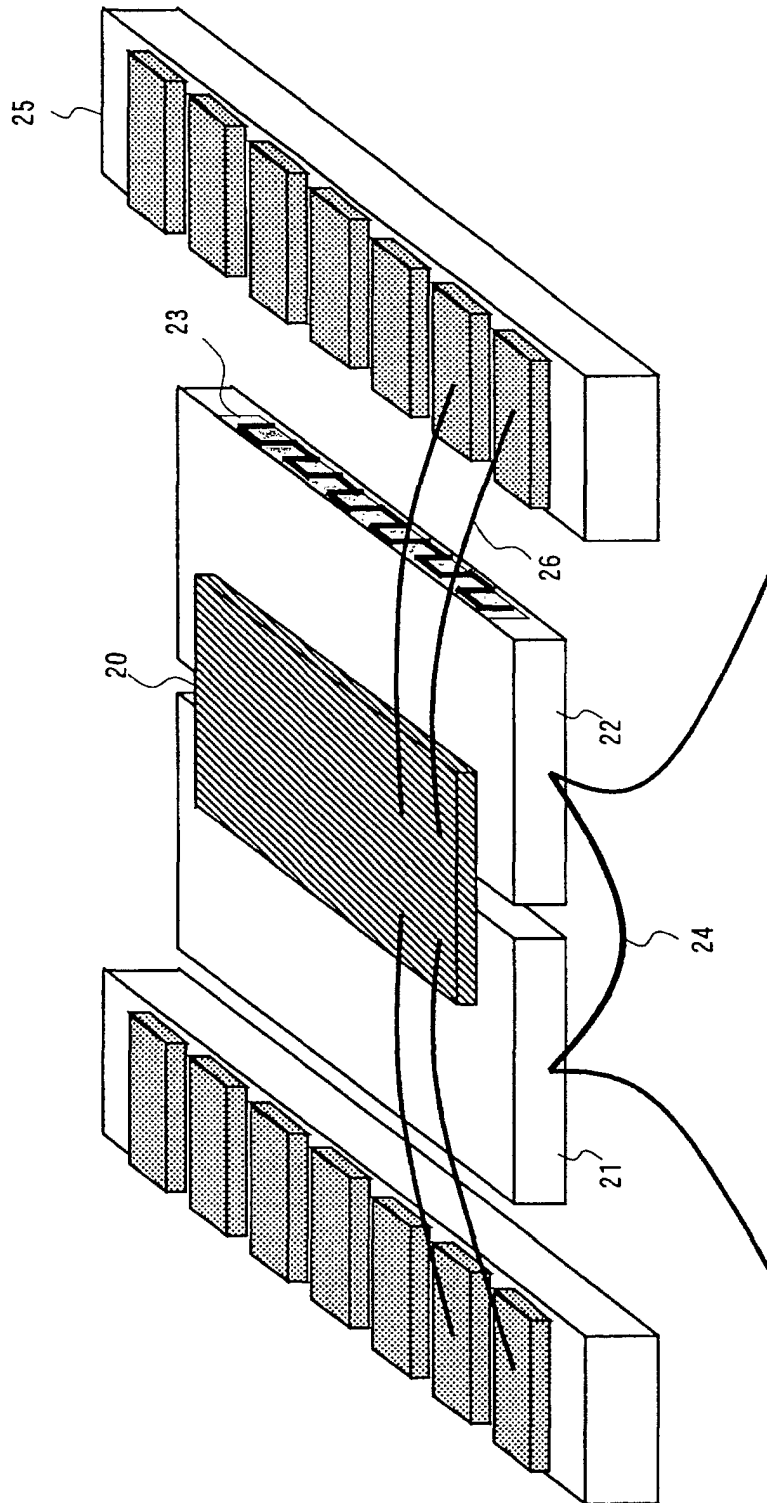
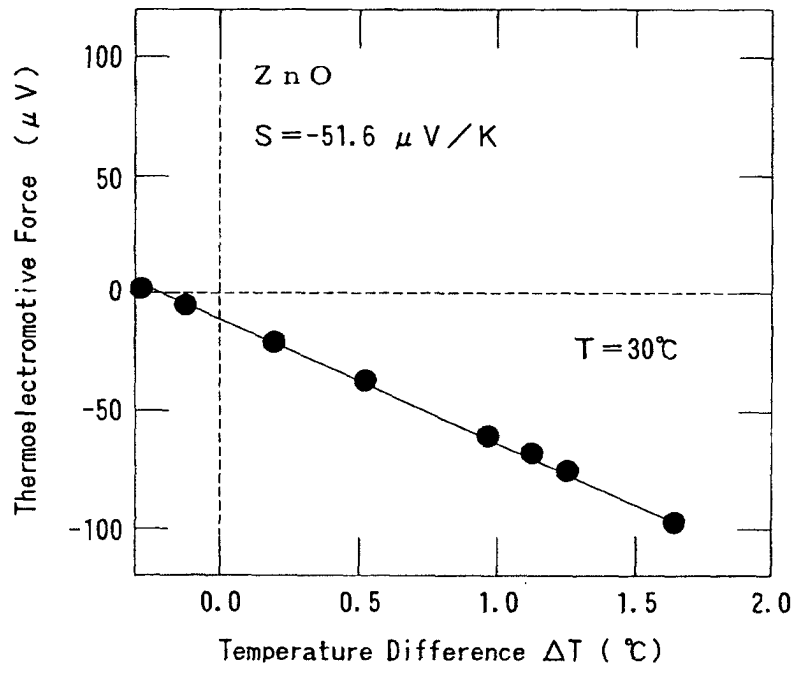


FIG. 4



INTERNATIONAL SEARCH REPORT

International application No.

PCT/JP02/02415

A. CLASSIFICATION OF SUBJECT MATTER Int.Cl. ⁷ G01N27/00		
According to International Patent Classification (IPC) or to both national classification and IPC		
B. FIELDS SEARCHED		
Minimum documentation searched (classification system followed by classification symbols) Int.Cl. ⁷ G01N27/00-27/24, G01R27/00-27/32, H01L21/66		
Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched Jitsuyo Shinan Koho 1922-1996 Toroku Jitsuyo Shinan Koho 1994-2002 Kokai Jitsuyo Shinan Koho 1971-2002 Jitsuyo Shinan Toroku Koho 1996-2002		
Electronic data base consulted during the international search (name of data base and, where practicable, search terms used) JICST FILE (JOIS)		
C. DOCUMENTS CONSIDERED TO BE RELEVANT		
Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	JP 5-52783 A (Tokuyama Soda Co., Ltd.), 02 March, 1993 (02.03.93), Full text; Figs. 1 to 14 (Family: none)	1-2
A	JP 9-222403 A (Hitachi, Ltd.), 26 August, 1997 (26.08.97), Full text; Figs. 1 to 11 (Family: none)	1-2
A	JP 10-512840 A (The Regents of the University of California), 08 December, 1998 (08.12.98), Full text; Figs. 1 to 27 & WO 96/11878 A1 & EP 789671 A & US 5776359 A	1-2
<input checked="" type="checkbox"/> Further documents are listed in the continuation of Box C. <input type="checkbox"/> See patent family annex.		
* Special categories of cited documents: "A" document defining the general state of the art which is not considered to be of particular relevance "E" earlier document but published on or after the international filing date "L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) "O" document referring to an oral disclosure, use, exhibition or other means "P" document published prior to the international filing date but later than the priority date claimed		"I" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention "X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art "&" document member of the same patent family
Date of the actual completion of the international search 06 June, 2002 (06.06.02)		Date of mailing of the international search report 18 June, 2002 (18.06.02)
Name and mailing address of the ISA/ Japanese Patent Office		Authorized officer
Facsimile No.		Telephone No.

Form PCT/ISA/210 (second sheet) (July 1998)

INTERNATIONAL SEARCH REPORT

International application No.

PCT/JP02/02415

C (Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT		
Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	Hideomi KOINUMA et al., 21 Seiki no Zairyo Kakumei Sento Program (Combinatorial Gijutsu) 1000nen o Inen ni Chijimeru Material Highway no Kochiku... Comet, Materials Integration, 25 July, 2000 (25.07.00), Vol.13, No.8, pages 39 to 44	1-2

Form PCT/ISA/210 (continuation of second sheet) (July 1998)